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# Hyperfast Rectifier, 2 x 15 FRED Pt<sup>®</sup>





PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 15 A					
V <sub>R</sub>	200 V					
V <sub>F</sub> at I <sub>F</sub>	0.78 V					
t <sub>rr</sub> typ.	See Recovery table					
T <sub>J</sub> max.	175 °C					
Package	3L TO-220 FullPAK					
Circuit configuration	Common cathode					

## FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package ( $V_{INS} = 2500 V_{RMS}$ )
- UL pending
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **DESCRIPTION / APPLICATIONS**

200 V series are the state of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage		V <sub>RRM</sub>		200	V		
Average rectified forward current	per diode	I <sub>F(AV)</sub>	T <sub>C</sub> = 125 °C	15			
Average rectilied forward current	per device			30	А		
Non-repetitive peak surge current		I <sub>FSM</sub>	$T_J = 25 \ ^\circ C$	200			
Operating junction and storage temperation	atures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	200	-	-			
	M	I <sub>F</sub> = 15 A	-	0.92	1.05	V		
Forward voltage V <sub>F</sub>		I <sub>F</sub> = 15 A, T <sub>J</sub> = 125 °C	-	0.78	0.85			
Deverse leekege eurrent		$V_{R} = V_{R}$ rated	-	-	10			
Reverse leakage current I <sub>R</sub>		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	5	300	μA		
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	57	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH		

Revision: 26-Oct-17 1 Document Number: 96433 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_C = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
			$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	35		
Reverse recovery time t <sub>rr</sub>		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100$	-	-	30			
	۲r	T <sub>J</sub> = 25 °C		-	26	-	ns	
		T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 160 V	-	40	-		
Deals receivers ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	2.8	-	А	
Peak recovery current		T <sub>J</sub> = 125 °C		-	6.0	-	~	
	0	T <sub>J</sub> = 25 °C		-	37	-		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C	-	120	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C		
Thermal resistance, junction-to-case per diode	R <sub>thJC</sub>	Mounting surface, flat, smooth and greased	-	-	3.5	°C/W		
Marking device		Case style 3L TO-220 FullPAK	30CTH02FP					

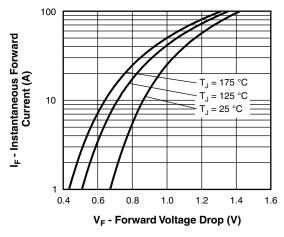


Fig. 1 - Typical Forward Voltage Drop Characteristics

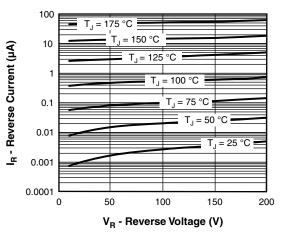


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



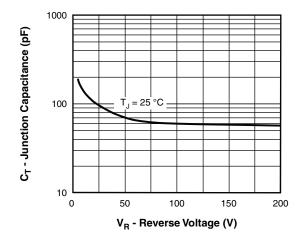


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

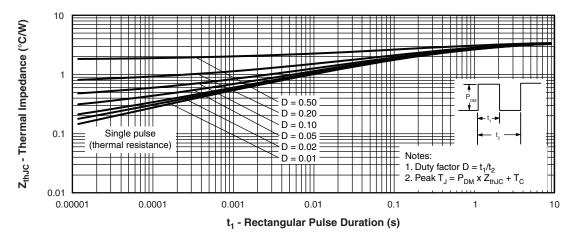
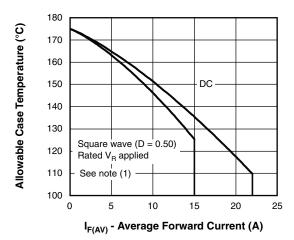
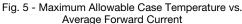


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \\ \end{array}$ 

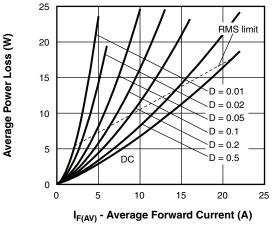


Fig. 6 - Forward Power Loss Characteristics

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# VS-30CTH02FP-N3

## **Vishay Semiconductors**

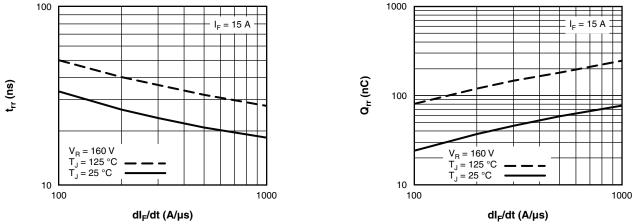


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt



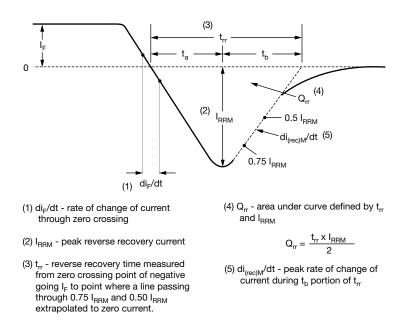


Fig. 9 - Reverse Recovery Waveform and Definitions



## **ORDERING INFORMATION TABLE**

Device and				•	_				
Device code	VS-	3	80	С	T	н	02	FP	-N3
			2	3	4	5	6	7	8
	1	_	Visł	nav Sem	iconduc	tors pro	oduct		
	2	-		-	ng (30 =				
	3	-	C =	commo	on catho	de			
	4	-	T =	TO-220					
	5	-	H =	hyperfa	st reco	very			
	6	-	Volt	age rati	ng (02 =	200 V)			
	7	-	FP =	= 3L TO	-220 Fu	IPAK			
	8	-	Env	ironmen	ital digit	:			
			-N3	= halog	en-free	RoHS-	complia	ant, and	l totally

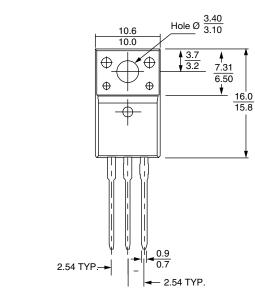
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-20CTH03FP-N3	50	1000	Antistatic plastic tube			

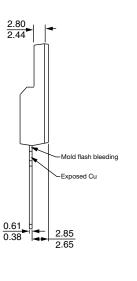
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96155				
Part marking information	www.vishay.com/doc?95456				

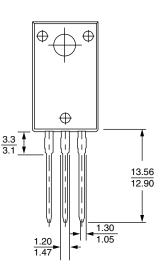


# 3L TO-220 FullPAK

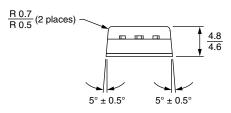
## **DIMENSIONS** in millimeters







Bottom view



#### Notes

- <sup>(1)</sup> All dimensions are in mm
- <sup>(2)</sup> Package body size exclude mold flash and burrs. Moldflash should be less than 6 mils



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